

20V N-Channel Signal MOSFET

Features

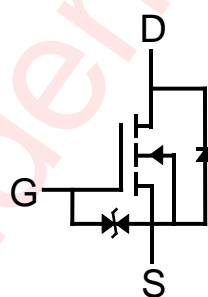
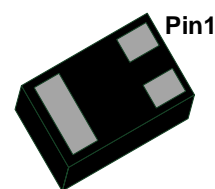
- N-Channel Switch with Low $R_{DS(ON)}$
- Lead Free Product is Acquired
- Operated at Low Logic Level Gate Drive
- ESD protected
- DFN1006-1mm X0.6mm X0.45mm-3L

Applications

- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable Electronics
- Logic Level Shift

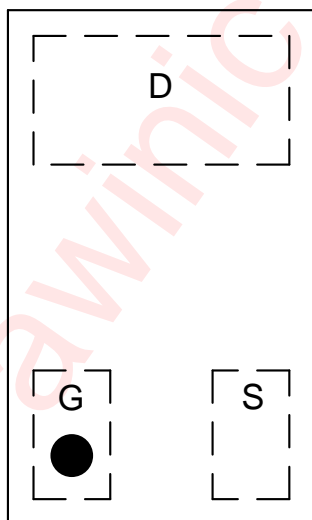
General Description

Product Summary	
V_{DS}	20V
$R_{DS(ON)}$	240m Ω (Typ.)@ $V_{GS}=2.5V$
	190m Ω (Typ.)@ $V_{GS}=4.5V$
I_D	0.7A

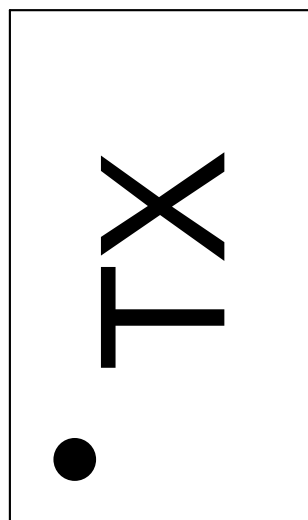
**DFN1006****Bottom View**

Pin Configuration and Top Mark

AW402015NDNR
(Top View)



AW402015NDNR Marking
(Top View)



T---AW402015NDNR
X---Production Tracing Code

Ordering Information

Part Number	Package	Marking	Moisture Sensitivity Level	Environmental Information	Delivery Form
AW402015NDNR	DFN 1mmX0.6mm X0.45mm -3L	T	MSL1	RoHS +HF	10000 units / Tape and Reel

Absolute Maximum Ratings (NOTE 1)

Symbol	Parameter	Rating	Unit
V_{DS}	Drain-Source Voltage	20	V
V_{GS}	Gate-Source Voltage	± 10	V
I_D	Drain Current(DC) (NOTE 5)	0.7	A
I_{DM}	Drain Current(Pulse) (NOTE 3)	1.8	A
P_D	Power Dissipation	0.1	W
T_J	Maximum Operating Junction Temperature	150	°C
T_{STG}	Storage Temperature	-55 ~ 150	°C
V_{ESD}	Human Body Model (NOTE 6)	± 1	kV

Thermal Information

Symbol	Parameter	Condition	Value	Unit
$R_{\theta JA}$	Maximum Junction to Ambient (NOTE 2, 4)	Steady-State	625	°C/W

NOTE1: Conditions out of those ranges listed in "absolute maximum ratings" may cause permanent damages to the device. In spite of the limits above, functional operation conditions of the device should within the ranges listed in "recommended operating conditions". Exposure to absolute-maximum-rated conditions for prolonged periods may affect device reliability.

NOTE2: Mounted on FR-4 material with the minimum recommended pad size.

NOTE3: Test condition 10 μ s 25°C.

NOTE4: Thermal resistance from junction to ambient is highly dependent on PCB layout.

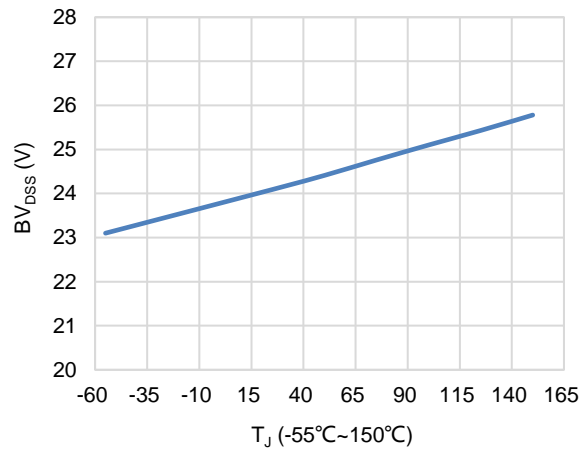
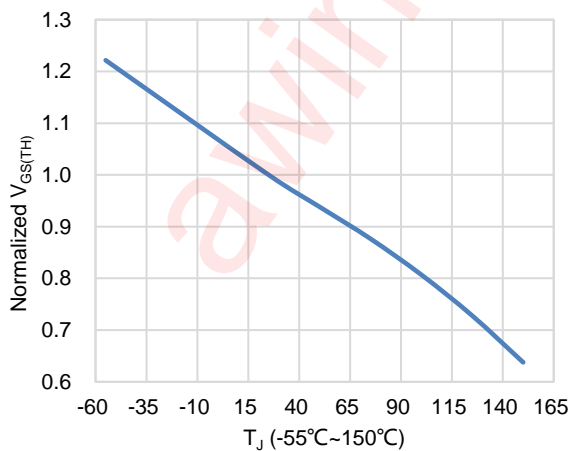
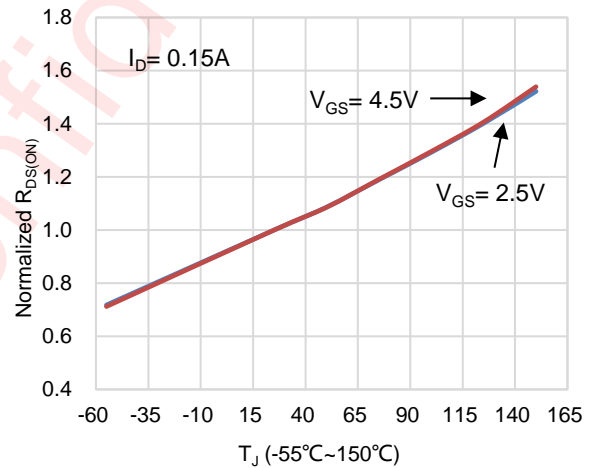
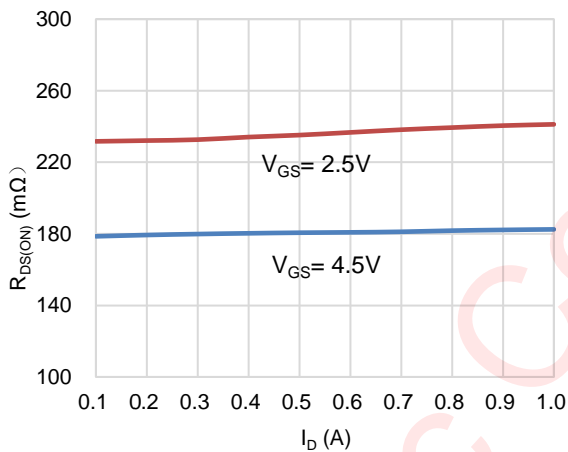
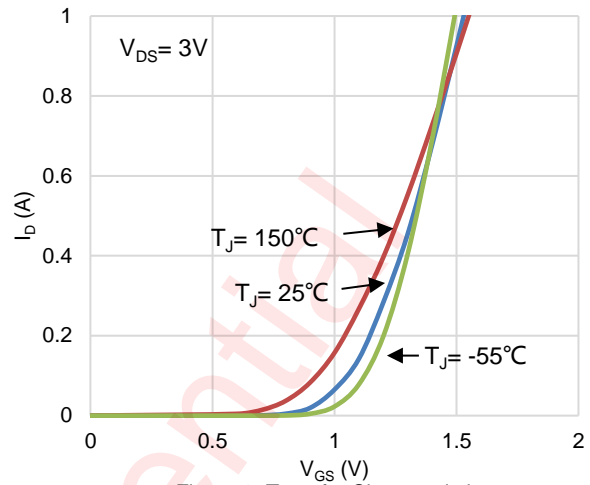
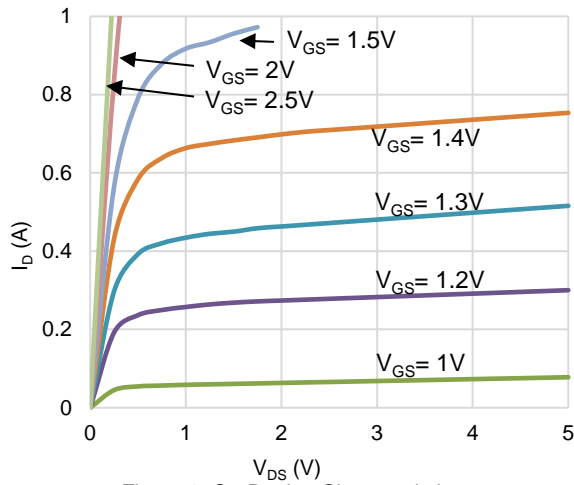
NOTE5: Rated according to $R_{\theta JA}$.

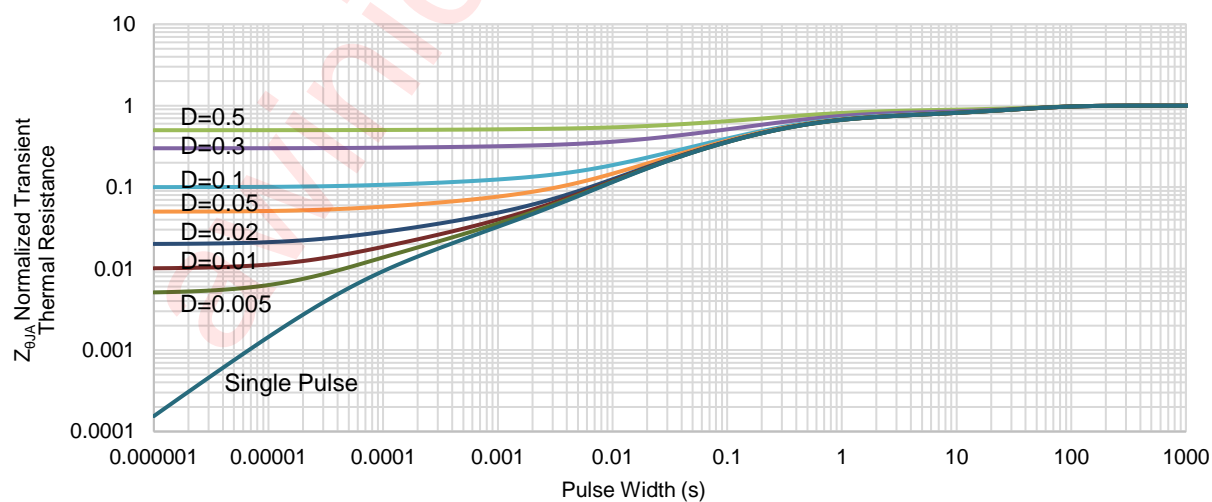
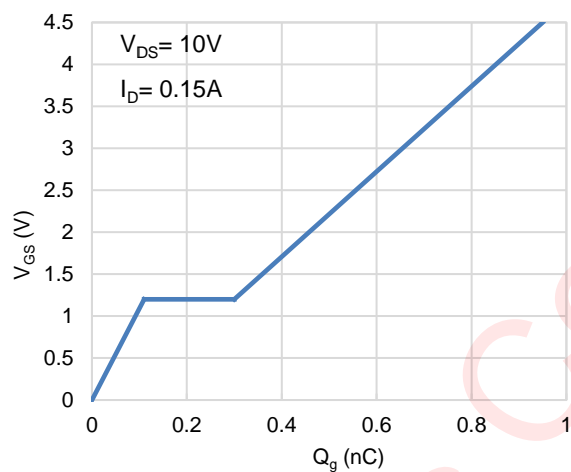
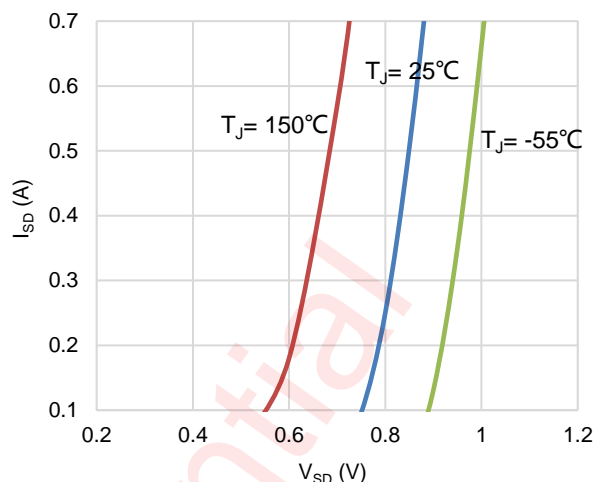
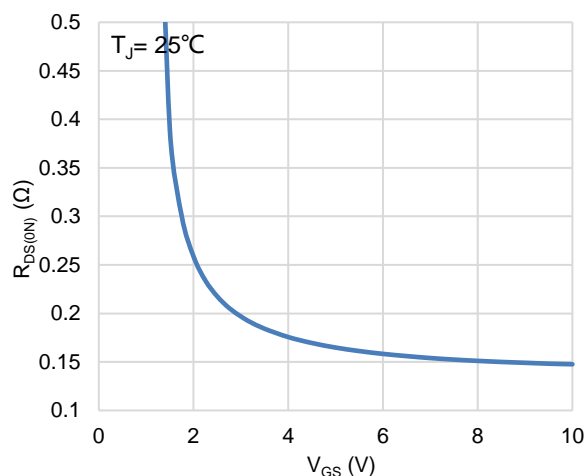
NOTE6: HBM Standards: ESDA/JEDEC JS-001-2017.

Electrical Characteristics

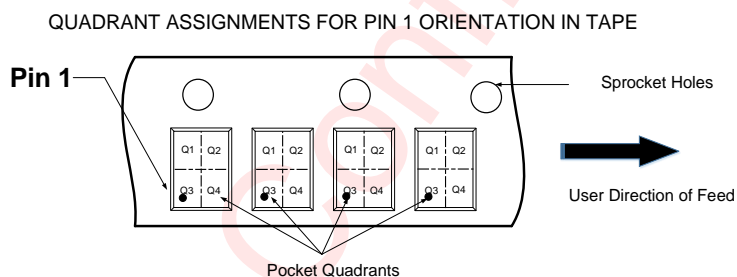
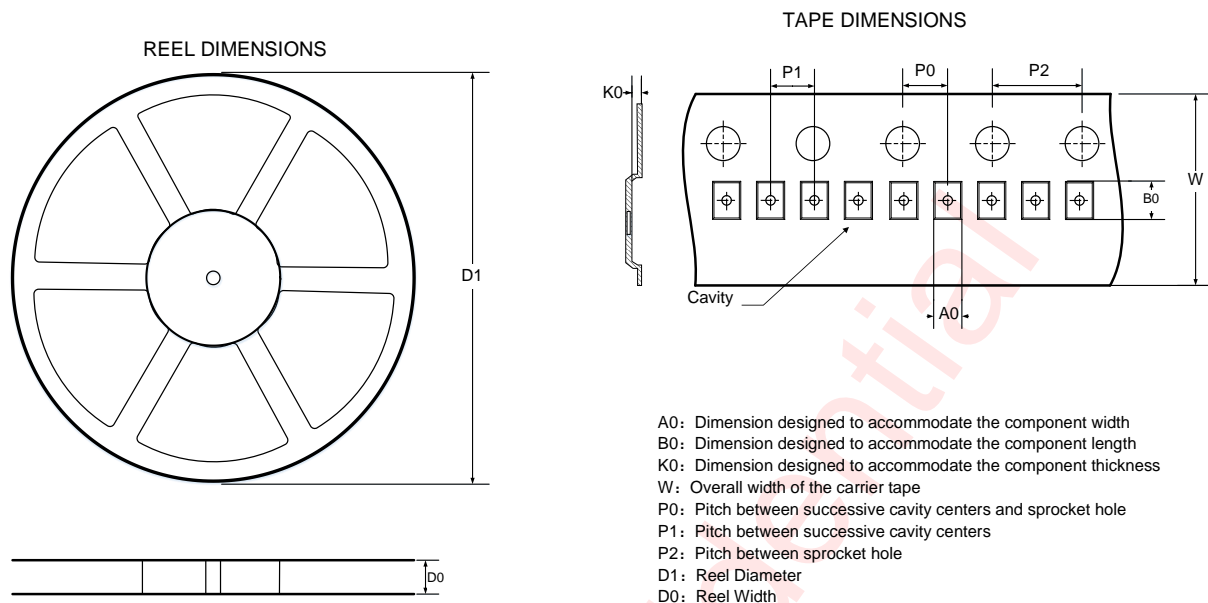
Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
STATIC PARAMETERS						
BV _{DSS}	Drain-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	20	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 20V, V _{GS} = 0V	-	-	1	μA
I _{GSS}	Gate Leakage Current	V _{DS} = 0V, V _{GS} = ±10V	-	-	±20	μA
V _{GS(TH)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250μA	0.35	-	1.1	V
R _{DS(ON)}	Static Drain to Source On-Resistance	V _{GS} = 4.5V, I _D = 0.15A	-	190	300	mΩ
		V _{GS} = 2.5V, I _D = 0.15A	-	240	390	mΩ
		V _{GS} = 1.8V, I _D = 0.15A		380	570	mΩ
V _{SD}	Diode Forward Voltage	I _S = 0.15A, V _{GS} = 0V	-	0.8	1.2	V
DYNAMIC PARAMETERS						
R _g	Gate Resistance	f= 1MHz	-	45	-	Ω
C _{iss}	Input Capacitance	V _{GS} = 0V, V _{DS} = 16V, f= 1MHz	-	51	-	pF
C _{oss}	Output Capacitance		-	11	-	pF
C _{rss}	Reverse Transfer Capacitance		-	11	-	pF
SWITCHING PARAMETERS						
Q _g	Total Gate Charge	V _{DS} = 10V, V _{GS} = 4.5V, I _D = 0.15A	-	0.96	-	nC
Q _{gs}	Gate Source Charge		-	0.11	-	nC
Q _{gd}	Gate Drain Charge		-	0.19	-	nC
t _{d(on)}	Turn-On Delay Time	V _{DS} = 10V, R _g = 10Ω, I _D = 500mA V _{GS} = 4.5V,	-	5.2	-	ns
t _r	Turn-On Rise Time		-	4.3	-	ns
t _{d(off)}	Turn-Off Delay Time		-	18.5	-	ns
t _f	Turn-Off Fall Time		-	8.3	-	ns

Typical Electrical and Thermal Characteristics





Tape and Reel Information



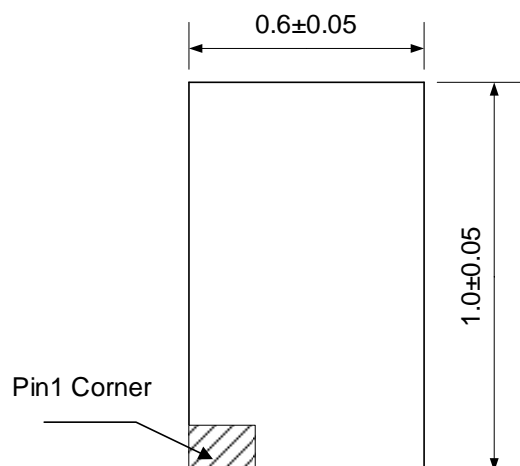
Note: The above picture is for reference only. Please refer to the value in the table below for the actual size

DIMENSIONS AND PIN1 ORIENTATION

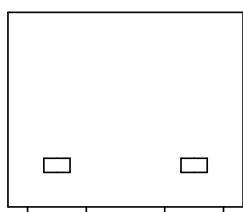
D1 (mm)	D0 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
178	9.5	0.72	1.17	0.55	2	2	4	8	Q3

All dimensions are nominal

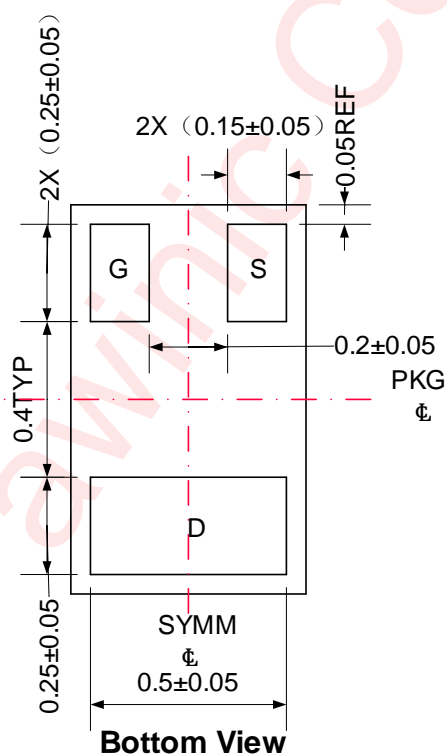
Package Description



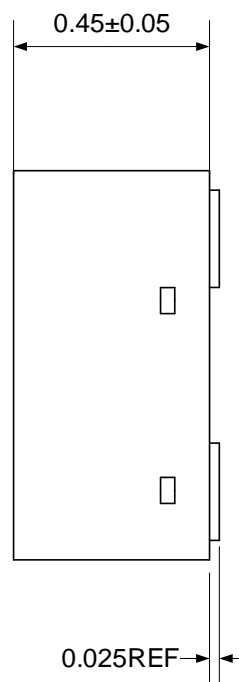
Top View



Side View



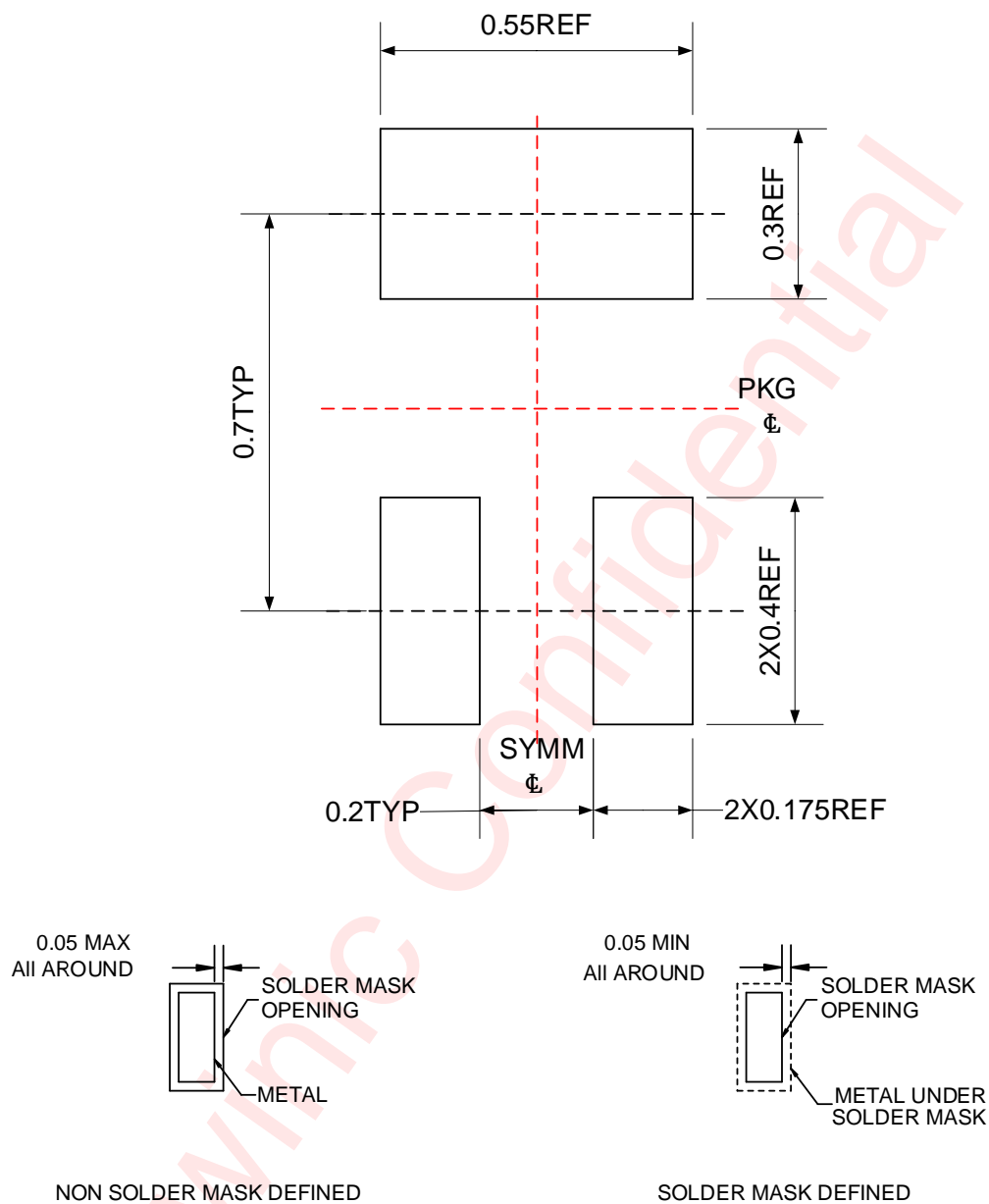
Bottom View



Side View

Unit: mm

Land Pattern Data



Unit: mm

Revision History

Version	Date	Change Record
V1.0	Nov. 2022	Official released
V1.1	Feb. 2023	Updated Land Pattern Data. (P8)

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